

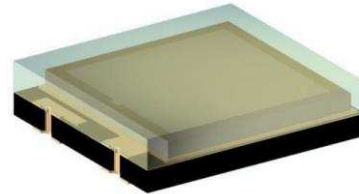
General Description

OIPV6 consists in a photovoltaic cell, 4x4mm, packaged in CSP (Chip Scaled Package). The package type enhance the fill factor of the component. The device is the ideal solution as harvesting “brick” for smart systems, sensors and electronics. The cell efficiency is very high allowing the user to extract more current than from normal cells. The OIPV6 is a simple element, which can be assembled as a classic SMT component: it can be combined in series and/or in parallel, in order to achieve the desired voltage and current.

OIPV6 can be purchased with 2 options, concerning the encapsulant resin, depending on requirements.

The silicone encapsulant ensures very high temperature ranges (ideal for concentration applications) and very low degradation due to aging. The silicone offers also better mechanical properties, as it is elastic.

The epoxy resin encapsulant is very clear, it offers a good hardness (75 shore D), it is insensible to dust in comparison to silicone and it has very high optical transmission index. The drawback of epoxy covering resin is that it is delicate to the temperature shocks.



Features

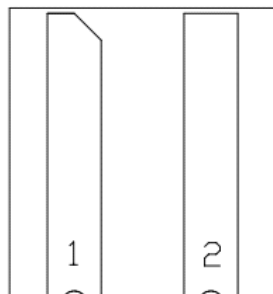
- High efficiency cell (20 at 1 sun)
- Output current linear with concentration factor
- Textured surface
- No contact degradation (no aging of the metal contacts)
- Compliant to RoHS European Directive
- Suitable also for concentrated light up to 150X
- Available with different encapsulants (silicone or clear epoxy)

Applications

Harvesting modules
 Concentration photovoltaic systems
 Solar rechargeable systems
 Green power production

Pin Functions

No.	Name	Function
1	C	Cathode
2	A	Anode



back view

Ordering Information

OIPV6-S Photovoltaic cell in CSP 4x4mm silicone cover
 OIPV6-E Photovoltaic cell in CSP 4x4mm epoxy cover

OIPV6

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit
T _A	Max Operating Temperature (S version)	-30	100	°C
	Max Operating Temperature (E version)	-20	70	°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

T_A = 25°C, unless otherwise noted.

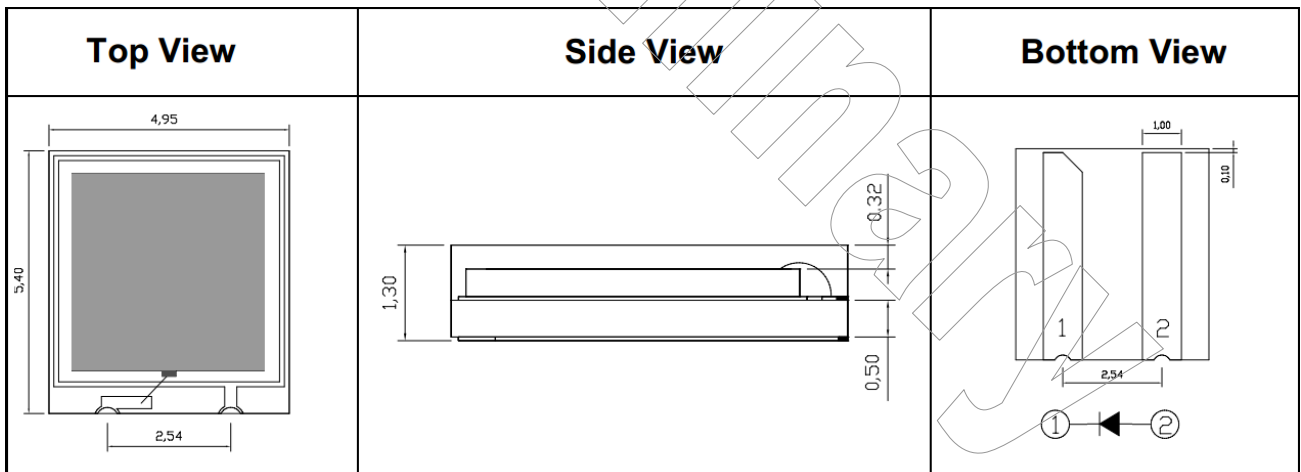
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T _A	Operating Temperature Range		0		70	°C
	Operating Temperature Range		-25		85	°C
V _{oc}	Open circuit voltage			0.625		V
I _{sc}	Short circuit current			39		mA/cm ²
E	Efficiency	1 SUN		20		
		100 SUN		24		

MECHANICAL CHARACTERISTICS

T_A = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
A	Active area			0.13		cm ²
FF _c	Fill factor of the cell			82.3		%
FF _p	Fill factor of packaged device	Including the package		50		%
H	Hardness of the resin	S version, shore D		75		
		E version, shore A		29		

MECHANICAL DIMENSIONS



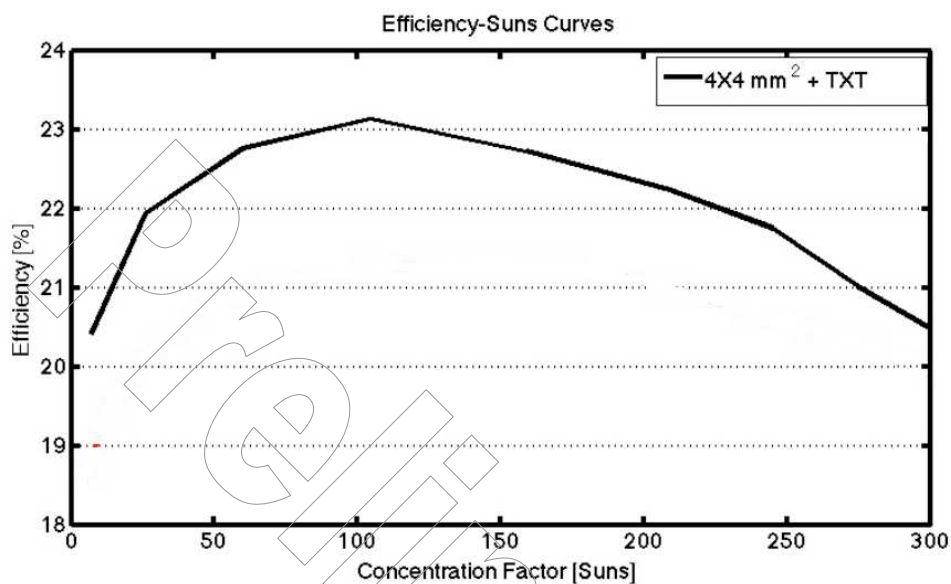


Figure 1 – efficiency VS concentration factor

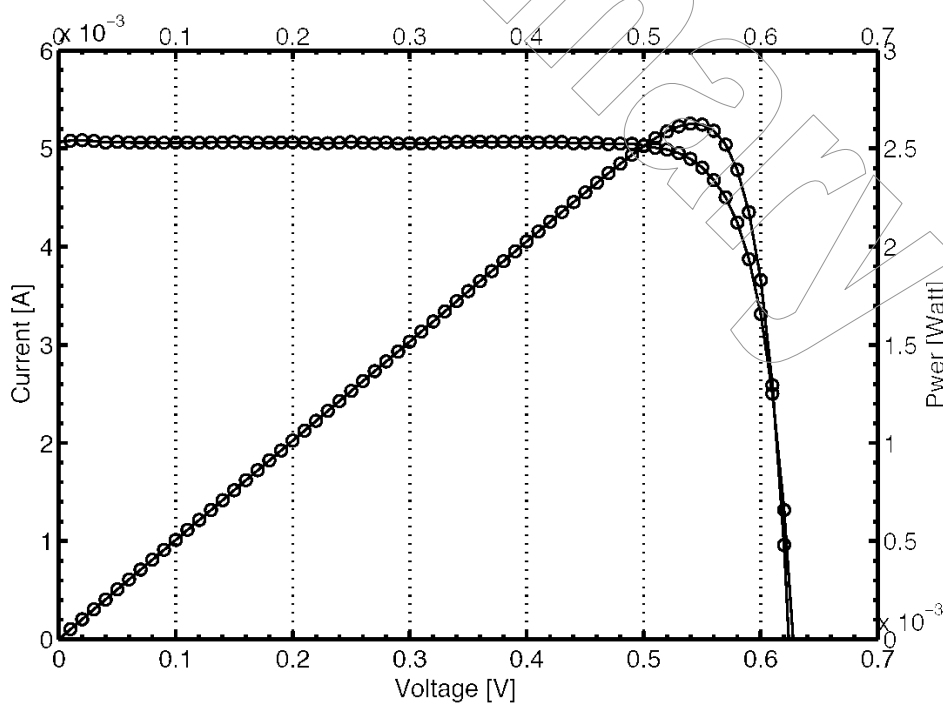


Figure 2 – I-V characteristic, conversion efficiency